

Bipolar Transistors Silicon PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

# RN2101MFV/02MFV/03MFV/04MFV/05MFV/06MFV

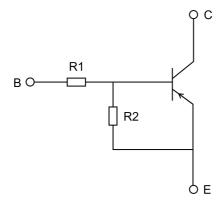
#### 1. Applications

- · Switching
- · Inverter Circuits
- · Interfacing
- · Driver Circuits

#### 2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Ultra-small package, suited to very high density mounting
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.
- (4) Toshiba offers transistors with a wide range of resistance to accommodate various circuit designs.
- (5) Complementary to RN1101MFV to RN1106MFV

#### 3. Equivalent Circuit



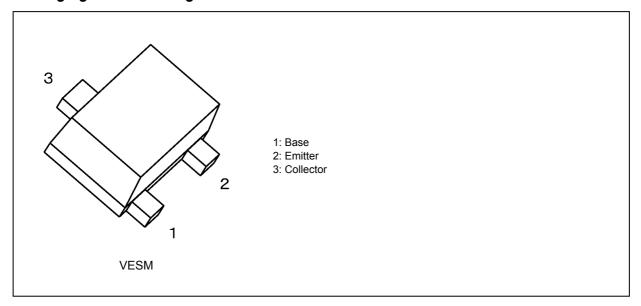
#### 4. Bias Resistor Values

Part No.	R1 (kΩ)	R2 (kΩ)
RN2101MFV	4.7	4.7
RN2102MFV	10	10
RN2103MFV	22	22
RN2104MFV	47	47
RN2105MFV	2.2	47
RN2106MFV	4.7	47

Start of commercial production



### 5. Packaging and Pin Assignment



### 6. Orderable part number

Orderable part number		AEC-Q101	AEC-Q101		Note		
RN2101MFV	RN2101MFV,L3F	_		General Use			
	RN2101MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2101MFV,L3XHF	YES		Automotive Use			
RN2102MFV	RN2102MFV,L3F	_		General Use			
	RN2102MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2102MFV,L3XHF	YES		Automotive Use			
RN2103MFV	RN2103MFV,L3F	_		General Use			
	RN2103MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2103MFV,L3XHF	YES		Automotive Use			
RN2104MFV	RN2104MFV,L3F	_		General Use			
	RN2104MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2104MFV,L3XHF	YES		Automotive Use			
RN2105MFV	RN2105MFV,L3F	_		General Use			
	RN2105MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2105MFV,L3XHF	YES		Automotive Use			
RN2106MFV	RN2106MFV,L3F	_		General Use			
	RN2106MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2106MFV,L3XHF	YES		Automotive Use			

Note 1: For more information, please contact our sales or use the inquiry form on our website.



#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

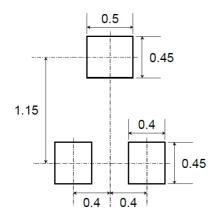
Characteristics		Symbol	Rating	Unit
Collector-base voltage	RN2101MFV to RN2106MFV	V <sub>CBO</sub>	-50	V
Collector-emitter voltage		V <sub>CEO</sub>	-50	
Emitter-base voltage	RN2101MFV to RN2104MFV	$V_{EBO}$	-10	
	RN2105MFV,RN2106MFV		-5	
Collector current	RN2101MFV to RN2106MFV	I <sub>C</sub>	-100	mA
Collector power dissipation		P <sub>C</sub> (Note 1)	150	mW
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board (25.4 mm × 25.4 mm × 1.6 mm)

#### 8. Land Pattern Dimensions (for reference only)



Unit: mm



## 9. Electrical Characteristics (Unless otherwise specified, $T_a$ = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2101MFV to	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_{E} = 0 \text{ mA}$	_	_	-100	nA
	RN2106MFV	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{B} = 0 \text{ mA}$	_	_	-500	
Emitter cut-off current	RN2101MFV	I <sub>EBO</sub>	$V_{EB} = -10 \text{ V}, I_{C} = 0 \text{ mA}$	-0.82	_	-1.52	mA
	RN2102MFV			-0.38	_	-0.71	
	RN2103MFV			-0.17	_	-0.33	
	RN2104MFV			-0.082	_	-0.15	
	RN2105MFV		V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0 mA	-0.078	_	-0.145	
	RN2106MFV			-0.074	_	-0.138	
DC current gain	RN2101MFV	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	30	_	_	_
	RN2102MFV			50	_	_	
	RN2103MFV			70	_	_	
	RN2104MFV			80	_	_	
	RN2105MFV			80	_	_	
	RN2106MFV			80	_	_	
Collector-emitter saturation voltage	RN2101MFV to RN2106MFV	V <sub>CE(sat)</sub>	I <sub>C</sub> = -5 mA, I <sub>B</sub> = -0.5 mA	_	-0.1	-0.3	V
Input voltage (ON)	RN2101MFV	V <sub>I(ON)</sub>	$V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$	-1.1	_	-2.0	V
	RN2102MFV			-1.2	_	-2.4	
	RN2103MFV			-1.3	_	-3.0	
	RN2104MFV			-1.5	_	-5.0	
	RN2105MFV			-0.6	_	-1.1	
	RN2106MFV			-0.7	_	-1.3	
Input voltage (OFF)	RN2101MFV to RN2104MFV	V <sub>I(OFF)</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$	-1.0	_	-1.5	V
	RN2105MFV, RN2106MFV			-0.5	_	-0.8	
Collector output capacitance	RN2101MFV to RN2106MFV	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	0.9	_	pF
Input resistance	RN2101MFV	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ
	RN2102MFV	R <sub>1</sub>	]	7	10	13	kΩ
	RN2103MFV			15.4	22	28.6	
	RN2104MFV			32.9	47	61.1	
	RN2105MFV			1.54	2.2	2.86	
	RN2106MFV			3.29	4.7	6.11	
Resistor ratio	RN2101MFV to RN2104MFV	R1/R2	-	0.8	1.0	1.2	_
	RN2105MFV	R1/R2	1	0.0376	0.0468	0.0562	_
	RN2106MFV			0.08	0.1	0.12	



#### 10. Marking

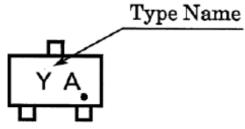


Fig. 10.1 Marking RN2101MFV

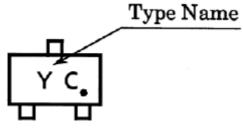


Fig. 10.3 Marking RN2103MFV

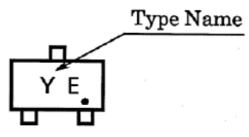


Fig. 10.5 Marking RN2105MFV

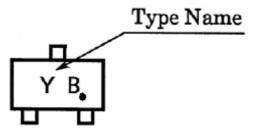


Fig. 10.2 Marking RN2102MFV

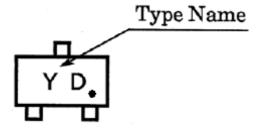


Fig. 10.4 Marking RN2104MFV

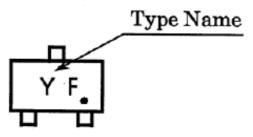


Fig. 10.6 Marking RN2106MFV



#### 11. Characteristics Curves (Note)

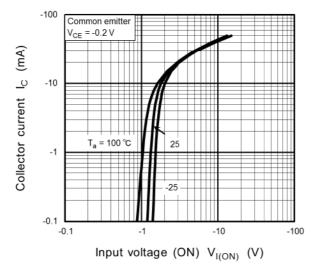


Fig. 11.1 RN2101MFV I<sub>C</sub>-V<sub>I(ON)</sub>

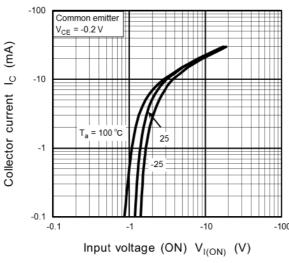


Fig. 11.3 RN2103MFV I<sub>C</sub>-V<sub>I(ON)</sub>

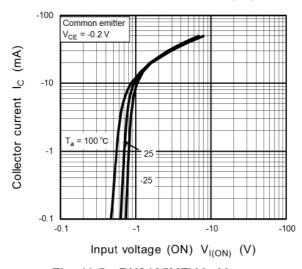


Fig. 11.5 RN2105MFV I<sub>C</sub>-V<sub>I(ON)</sub>

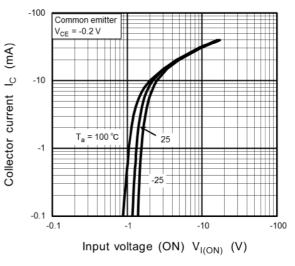


Fig. 11.2 RN2102MFV I<sub>C</sub>-V<sub>I(ON)</sub>

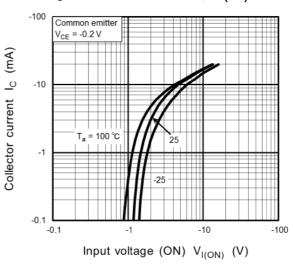


Fig. 11.4 RN2104MFV I<sub>C</sub>-V<sub>I(ON)</sub>

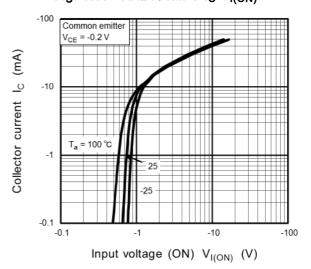


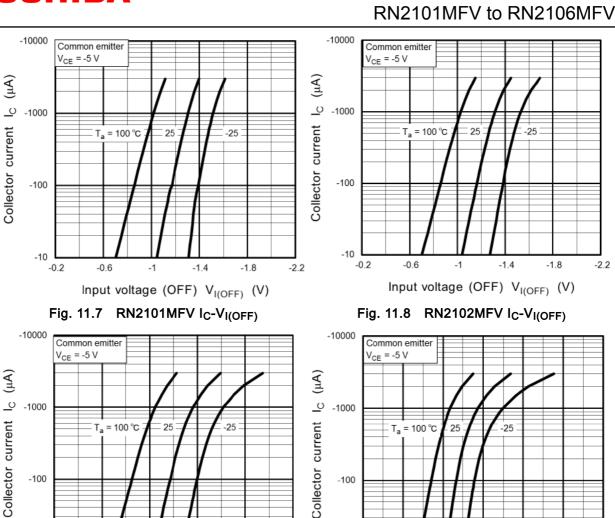
Fig. 11.6 RN2106MFV I<sub>C</sub>-V<sub>I(ON)</sub>



-10

-0.2

-0.6



-10

-0.5

Fig. 11.9 RN2103MFV I<sub>C</sub>-V<sub>I(OFF)</sub>

Input voltage (OFF) V<sub>I(OFF)</sub> (V)

-1.4

-1.8

-2.2

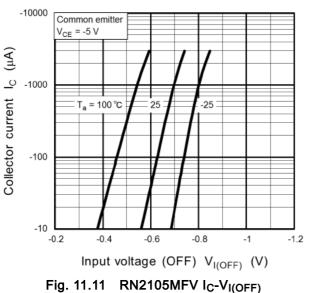


Fig. 11.10 RN2104MFV I<sub>C</sub>-V<sub>I(OFF)</sub>

-1.5

Input voltage (OFF) V<sub>I(OFF)</sub> (V)

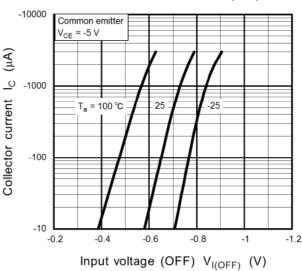
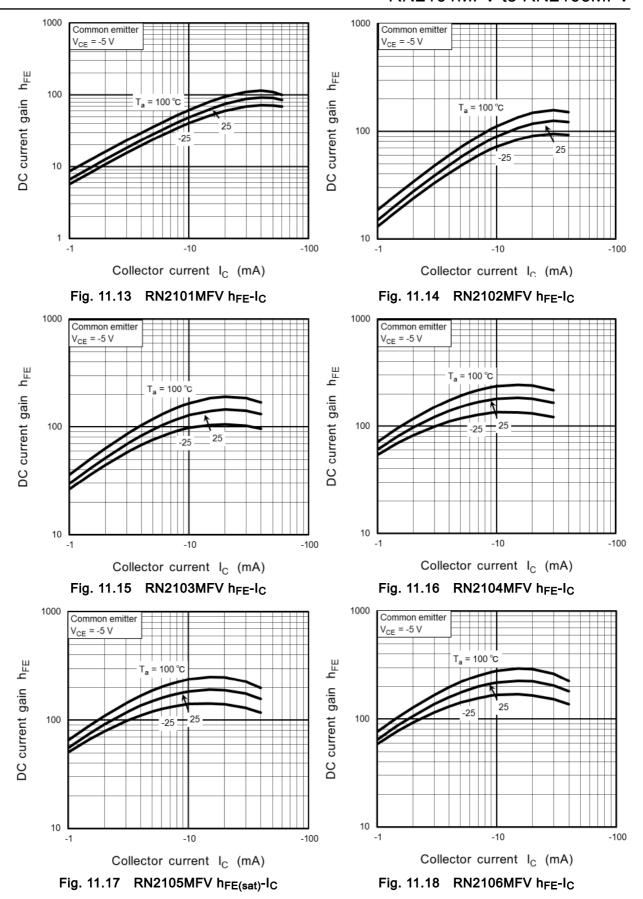


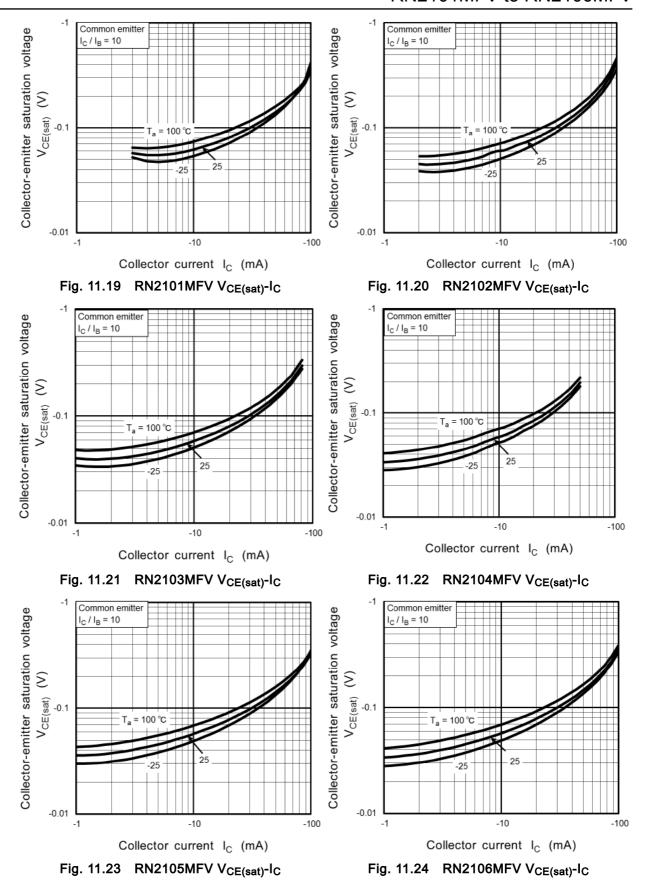
Fig. 11.12 RN2106MFV I<sub>C</sub>-V<sub>I(OFF)</sub>

Rev.6.0







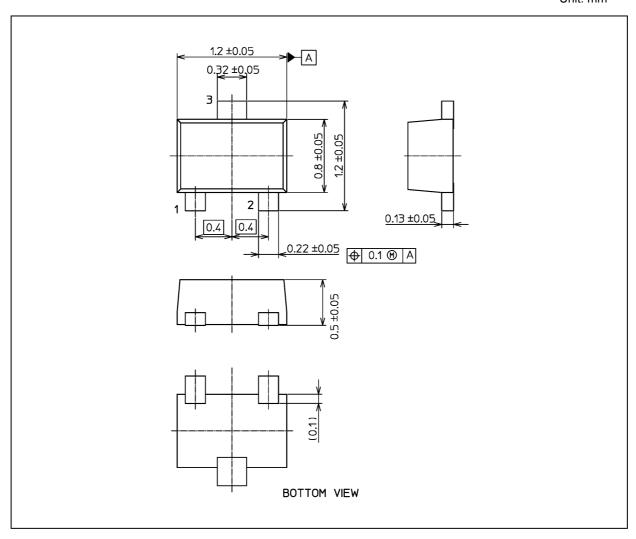


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 1.5 mg (typ.)

	Package Name(s)
TOSHIBA: 1-1Q1S	
Nickname: VESM	



#### **RESTRICTIONS ON PRODUCT USE**

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- · TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's
  written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications.
  TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").
  - Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant.
  - IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.

For details, please contact your TOSHIBA sales representative or contact us via our website.

- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER,
  INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS,
  INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS
  OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE,
  USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR
  A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
   Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

## **Toshiba Electronic Devices & Storage Corporation**

https://toshiba.semicon-storage.com/